

Lei Ni

List of Publications by Year in descending order

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Version: 2024-02-01

19
papers

678
citations

933447

10
h-index

794594

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g-index

20
all docs

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docs citations

20
times ranked

621
citing authors

#	ARTICLE	IF	CITATIONS
1	Effects of the in-plane uniaxial and biaxial strains on the structural and electronic properties of the monolayer ZrS ₂ : A first-principles investigation. <i>Thin Solid Films</i> , 2022, 755, 139343.	1.8	5
2	High Dielectric Constant and Dielectric Relaxations in La _{2/3} Cu ₃ Ti ₄ O ₁₂ Ceramics. <i>Materials</i> , 2022, 15, 4526.	2.9	2
3	A theoretical design of photodetectors based on two-dimensional Sb/AlAs type-II heterostructures. <i>CrystEngComm</i> , 2021, 23, 1033-1042.	2.6	18
4	Effect of Sintering Process on Ionic Conductivity of Li _{7-x} La ₃ Zr _{2-x} Nb _x O ₁₂ (x = 0, 0.2, 0.4, 0.6) Solid Electrolytes. <i>Materials</i> , 2021, 14, 1671.	2.9	9
5	Type-II C ₂ N/ZnTe Van Der Waals Heterostructure: A Promising Photocatalyst for Water Splitting. <i>Advanced Materials Interfaces</i> , 2021, 8, 2002068.	3.7	17
6	Electric field and uniaxial strain tunable electronic properties of the InSb/InSe heterostructure. <i>Physical Chemistry Chemical Physics</i> , 2020, 22, 20712-20720.	2.8	23
7	Band alignment control in a blue phosphorus/C ₂ N van der Waals heterojunction using an electric field. <i>Physical Chemistry Chemical Physics</i> , 2020, 22, 5873-5881.	2.8	29
8	Type-II tunable SiC/InSe heterostructures under an electric field and biaxial strain. <i>Physical Chemistry Chemical Physics</i> , 2020, 22, 9647-9655.	2.8	32
9	Prediction of the terminations and Miller planes of the tetragonal zirconia thin films as a gate dielectric layer in integrated-circuit industry. <i>Surface and Interface Analysis</i> , 2019, 51, 774-782.	1.8	2
10	Dielectric relaxation and relevant mechanism in giant dielectric constant Sm _{2/3} Cu ₃ Ti ₄ O ₁₂ ceramics. <i>Journal of Materials Science: Materials in Electronics</i> , 2018, 29, 17737-17742.	2.2	17
11	Fabrication of Self-Powered Fast-Response Ultraviolet Photodetectors Based on Graphene/ZnO:Al Nanorod-Array-Film Structure with Stable Schottky Barrier. <i>ACS Applied Materials & Interfaces</i> , 2017, 9, 8161-8168.	8.0	97
12	Enhanced dielectric relaxations in spark plasma sintered CaCu ₃ Ti ₄ O ₁₂ ceramics. <i>Journal of Materials Science: Materials in Electronics</i> , 2017, 28, 10191-10198.	2.2	8
13	Giant dielectric response in Dy _{2/3} Cu ₃ Ti ₄ O ₁₂ ceramics. <i>Journal of Materials Science: Materials in Electronics</i> , 2016, 27, 111-117.	2.2	2
14	Solution-processable design strategy for a Li ₂ FeSiO ₄ @C/Fe nanocomposite as a cathode material for high power lithium-ion batteries. <i>RSC Advances</i> , 2014, 4, 35541-35545.	3.6	5
15	Phase Transition Domains in Ca-based Complex Perovskite Dielectric Ceramics. <i>Journal of the American Ceramic Society</i> , 2012, 95, 2979-2988.	3.8	5
16	Effects of Nd-substitution on microstructures and dielectric characteristics of CaCu ₃ Ti ₄ O ₁₂ ceramics. <i>Journal of Materials Science: Materials in Electronics</i> , 2011, 22, 345-350.	2.2	37
17	Enhancement of Giant Dielectric Response in CaCu ₃ Ti ₄ O ₁₂ Ceramics by Zn Substitution. <i>Journal of the American Ceramic Society</i> , 2010, 93, 184-189.	3.8	140
18	Dielectric relaxations and formation mechanism of giant dielectric constant step in CaCu ₃ Ti ₄ O ₁₂ ceramics. <i>Applied Physics Letters</i> , 2007, 91, .	3.3	221

#	ARTICLE	IF	CITATIONS
19	Evaluation of microwave dielectric properties of giant permittivity materials by a modified resonant cavity method. Applied Physics Letters, 2007, 91, 092906.	3.3	9